

ELECTRONIC VALVE SPECIFICATIONS
SPECIFICATION MOS/CV5060 ISSUE No. 2 DATED 1.3.59
AMENDMENT No. 2

- (i) Page 1. Specification Title: Delete 'MOS/CV5060'
and substitute MOA/CV5060'
- (ii) Page 2. Test Conditions: Amend 'Rg2=9.1k_Ω'
(inserted by Amendment No. 1) to read
'Rg2=11.1k_Ω'.
- (iii) Page 2. Test Clause (k) Screen Current: In the
column headed "Limits" amend Min., 4.2; Bogey,
5.5; and Max., 6.8; to read 3.4; 4.5; and
5.6 respectively.

T.V.C. Office for
R.A.E.

May, 1964

MINISTRY OF SUPPLY, D.L.R.D.(A)/R.A.E.

Specification MOS(A)/CV5060 Issue 1 Dated 9.11.56. To be read in conjunction with BS.448, BS.1409 and K1001	<u>SECURITY</u>	
	<u>Specification</u> UNCLASSIFIED	<u>Valve</u> UNCLASSIFIED

TYPE OF VALVE - Pentode Wide Band R.F. and Video Amplifier			<u>MARKING</u> See K1001/4		
CATHODE - Indirectly heated			<u>BASE</u> BS.448/B9A		
ENVELOPE - Glass					
PROTOTYPE - Z.759			<u>CONNECTIONS</u>		
<u>RATING</u> (All limiting values are absolute)					
			Pin	Electrode	
Heater Voltage	(V)	6.3	1	Cathode	k
Heater Current	(A)	0.6	2	Grid	g1
Max. Operating Anode Voltage	(V)	300	3	Cathode	k
Max. Operating Screen Voltage	(V)	250	4	No Conn.	NC
Max. Anode Dissipation	(W)	5	5	Heater	h
Max. Screen Dissipation	(W)	1.75	6	Heater	h
Max. Heater - Cathode Voltage	(V)	150	7	Anode	a
Max. Bulb Temperature	(°C)	250	8	Screen	g2
Mutual Conductance	(mA/V)	15	9	Supp.	g3
Anode Impedance	(MΩ)	0.5			
			<u>DIMENSIONS</u> See BS.448/B9A/2.1 Size Ref. No. 2		
<u>CAPACITANCES</u> (pF)			Dimensions (mm)		Min. Max.
C in (nom.)		13.0	A	seated height	- 49.0
C out (nom.)		3.0	B	diameter	19.0 22.2
Ca, g1 (max.)		0.015	B	overall length	- 56.0
			<u>MOUNTING POSITION</u> Any		
<u>NOTES</u>					
A. At $V_a = V_{g2} = 250V$; $I_a = 20 \text{ mA}$ ($V_{g1} = -2.0V$. $I_{g2} = 5.5 \text{ mA}$).					
B. With close fitting metal screen.					

Test Conditions - unless otherwise specified									
		Vh(V)	Va(V)	Vg2(V)	Vg3(V)	Ia(mA)			
		6.3	250	250	0	20			
	Test	Test Conditions	AQL	Insp. Level	Sym-bol	Limits			Units
						Min.	Bogey	Max.	
a	Electrode Insulation	Vh = 6.3V Note 1 Vg1 to all = -100V Vg2 to all = -300V Vg3 to all = -300V Va to all = -300V		100%	R	100	-	-	MΩ
				100%	R	100	-	-	MΩ
				100%	R	100	-	-	MΩ
				100%	R	100	-	-	MΩ
b	Reverse Grid Current	Rg1 = 500 kΩ max.		100%	Ig1	-	-	1.0	μA
c	Cathode Current	Va = Vg2 = Vg1 = 15V D.C.		100%	Ik	150	-	-	mA
d	Heater Current		1.5	I	Ih	540	600	660	mA
e	hk Leakage Current	Vhk = ± 100V Note 2	1.5	I	Ihk	-	-	10	μA
f	Mutual Conductance	Vg1 = -2V Grid Swing ± 0.5V	1.5	I	gm	11.2	15	18.3	mA/V
g	(1) g1 Volts	Ia = 20 mA	1.5	I	-Vg1	1.3	2.0	2.7	V
h	(2) g1 Volts	Ia = 0.2 mA	1.5	I	-Vg1	-	-	8.0	V
j	g3 Cut Off	Vg3 = -120V; Vg1 = -3.5V	1.5	I	Ia	-	-	100	μA
k	Screen Current		1.5	I	Ig2	4.1	5.5	6.9	mA
l	Capacitances	Measured on 1 Mc/s bridge. Valve mounted in a fully shielded socket. Valve screened	6.5	IC	C in C. out Ca, g1	11.4 2.4 -	13.0 3.0 -	14.6 3.6 0.015	pF pF pF

NOTES

1. Heater and Cathode strapped and considered as a single electrode.
2. Heater positive and negative successively.